NSN 5961-01-061-7530

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Demilitarization:

No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-061-7530 **Inclosure Material:** Metal **Overall Length:** Between 0.250 inches and 0.340 inches Overall Diameter: 0.620 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-66 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case and mounting hardware **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -275.0 collector to base voltage/static/emitter open and -225.0 collector to emitter voltage/static/base open and -6.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between -1.00 amperes source cutoff current and -2.00 amperes source cutoff current **Power Rating Per Characteristic:** 3.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Item must comply with rqmt of desc production standard no. L02508; for navy nuclear propulsion plant products only; junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 pin and 1 case Shelf Life: N/a **Unit Of Measure:**